
	<p><b>SI1012X-T1-E3</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1012X-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 20V 500MA SC89-3</p> <p><b>Datenblätter:</b>  <a href="#">SI1012X-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 30268 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI1012X-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 500MA SC89-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	30268 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-89, SOT-490
Supplier Device-Gehäuse	SC-89-3
Verlustleistung (max)	250mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	500mA (Ta)
Rds On (Max) @ Id, Vgs	700 mOhm @ 600mA, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)


















































SI1012X-T1-E3 ist neu im Original, Suche SI1012X-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1012X-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen.  
Anfrage SI1012X-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1012R-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 500MA SC-75A</p>	 <p><b>SI1013</b> SILICON SI1013 SILICON</p>	 <p><b>SI1012X-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 500MA SC89-3</p>	 <p><b>SI1012X</b> VISHAY SI1012X VISHAY</p>
 <p><b>SI1013-A-GM</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 42-WFQFN</p>	 <p><b>SI1012X-TE-E3</b> VISHAY VISHAY SOT-23</p>	 <p><b>SI1012X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 500MA SC89-3</p>	 <p><b>SI1012R-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 20V 500MA SC-75A</p>

### heiße Teile

Mehr

 SI1000-C-GM	 SI1002-C-GMR	 SI1003-C-GM	 SI1011X-T1-GE3	 SI1011X-T1-GE3
 SI1012CR-T1-GE3	 SI1012CR-T1-GE3	 SI1012R-T1	 SI1012R-T1-E3	 SI1012R-T1-E3
 SI1012R-T1-GE3	 SI1012R-T1-GE3	 SI1012X-T1	 SI1012X-T1-E3	 SI1012X-T1-GE3
 SI1012X-T1-GE3	 SI1013CX-T1-GE3	 SI1013CX-T1-GE3	 SI1013R-T1	 SI1013R-T1-E3
 SI1013R-T1-E3	 SI1013R-T1-GE3	 SI1013R-T1-GE3	 SI1013X-T1	 SI1013X-T1-E3
 SI1013X-T1-E3	 SI1013X-T1-GE3	 SI1013X-T1-GE3	 SI1016CX-T1-GE3	 SI1016CX-T1-GE3
 SI1016X-T1-E3	 SI1016X-T1-E3	 SI1016X-T1-GE3	 SI1016X-T1-GE3	 SI1016X2-T1-GE3
 SI1021R-T1	 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1	 SI1022R-T1-E3
 SI1022R-T1-E3	 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-T1-E3	 SI1023CX-T1-GE3
 SI1023CX-T1-GE3	 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3	 SI1023X-T1-GE3

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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